Theory of inelastic lifetimes of surface-state electrons and holes at metal surfaces

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After the early suggestion by John Pendry to probe unoccupied bands at surfaces through the time reversal of the photoemission process, the inverse-photoemission technique yielded the first conclusive experimental evidence for the existence of image-potential bound states at metal surfaces and has led over the last two decades to an active area of research in condensed-matter and surface physics. Here we describe the current status of the many-body theory of inelastic lifetimes of these image-potential states and also the Shockley surface states that exist near the Fermi level in the projected bulk band gap of simple and noble metals. New calculations of the self-energy and lifetime of surface states on Au surfaces are presented as well, by using the GWΓ approximation of many-body theory.

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I. INTRODUCTION

In a pioneering paper [\[1\]](#page-14-0), Echenique and Pendry investigated the observability of Rydberg-like electronic states trapped at metal surfaces via low-energy electron diffraction (LEED) experiments. They discussed the lifetime broadening of these image-potential-induced surface states (image states), and reached the important conclusion that they could, in principle, be resolved for all members of the Rydberg series.

A few years later, Pendry suggested a new experiment [\[2](#page-14-1)]: measurement of the bremsstrahlung-radiation spectrum from electrons, with energies no more than a few tens of electron volts, incident on clean surfaces, thereby turning incident electrons into emitted photons. This photon-emission experiment is simply the time reversal of the photoemission process and was referred to by Pendry as inverse photoemission, or IPE for short.

Subsequently, Johnson and Smith [\[3](#page-14-2)] pointed out that image states were potentially observable by angleresolved IPE; using this technique, Dose et al. [\[4\]](#page-14-3) and Straub and Himpsel [\[5](#page-14-4)] reported the first conclusive experimental evidence for image-potential bound states at the (100) surfaces of copper and gold. Since then, several observations of image states have been made using this technique $[6, 7, 8, 9, 10, 11, 12]$ $[6, 7, 8, 9, 10, 11, 12]$ $[6, 7, 8, 9, 10, 11, 12]$ $[6, 7, 8, 9, 10, 11, 12]$ $[6, 7, 8, 9, 10, 11, 12]$ $[6, 7, 8, 9, 10, 11, 12]$ $[6, 7, 8, 9, 10, 11, 12]$ $[6, 7, 8, 9, 10, 11, 12]$ $[6, 7, 8, 9, 10, 11, 12]$, and also the more recent high-resolution techniques of two-photon photoemission (2PPE) [\[13,](#page-14-12) [14,](#page-14-13) [15\]](#page-14-14) and time-resolved two-photon photoemission (TR-2PPE) [\[16,](#page-14-15) [17,](#page-14-16) [18](#page-14-17)]. In 2PPE, intense laser radiation is used to populate an unoccupied state with the first photon and to photoionize from the intermediate state with the second photon. In TR-2PPE, the probe pulse which ionizes the intermediate state is delayed with respect to the pump pulse which populates it, thus providing a direct measurement of the intermediatestate lifetime.

At metal surfaces, in addition to image states (which

FIG. 1: The ΓL projected bulk band structure (shaded areas) of the (111) and (100) surfaces of the noble metals Cu and Au. The solid lines represent Shockley $(n = 0)$ and imagepotential $(n = 1)$ surface-state bands. Well-defined Shockley states are only present at the $Cu(111)$ and $Au(111)$ surfaces, where the projected band gap extends below the Fermi level. Well-defined image states are present at the $Cu(100)$ and Au(100) surfaces, and also at the (111) surface of Cu. At Au(111) there is only an image-state resonance lying above the top of the band gap. The horizontal thin solid lines represent Fermi and vacuum levels.

are originated in the combination of the long-range image potential in front of solid surfaces with the presence of a band gap near the vacuum level) [\[19](#page-14-18), [20](#page-14-19)] there exist crystal-induced surface states (which would occur even for a step barrier in the absence of the image potential) [\[21](#page-14-20)] often classified as Shockley and Tamm states [\[22,](#page-14-21) [23\]](#page-14-22): Shockley states exist near the Fermi level in the projected bulk band gap of simple and noble met-

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als, and Tamm states exist at the \overline{M} points of the surface Brillouin zone for various noble-metal surfaces. The lifetimes of excited holes at the band edge $(\mathbf{k}_{\parallel} = 0)$ of Shockley states have been investigated with high-resolution angle-resolved photoemission (ARP) [\[24](#page-14-23), [25](#page-14-24), [26,](#page-14-25) [27](#page-14-26)] and with the use of the scanning tunneling microscope (STM) [\[28](#page-14-27), [29](#page-14-28)]. STM techniques have also allowed the determination of the lifetimes of excited Shockley and image electrons over a range of energies above the Fermi level [\[30,](#page-14-29) [31\]](#page-14-30).

Figure [1](#page-0-0) illustrates Shockley and image-potential states in the gap of the ΓL projected band structure of the (100) and (111) surfaces of the noble metals Cu and Au. If an electron or hole is added to the solid at one of these states, inelastic coupling of the excited quasiparticle with the crystal may occur through electron-electron (e-e) and electron-phonon (e-ph) scattering.

In this paper, we first give a brief description of existing calculations of e-ph inelastic linewidths of image and Shockley states, and we then focus on the many-body theory of e-e inelastic lifetimes of these states. In particular, we describe the current status of many-body GW and GWΓ calculations, and we report new GWΓ calculations of the self-energy and lifetime of surface states on Au surfaces. We conclude that short-range exchangecorrelation (xc) contributions to the electron (or hole) self-energy are small, as occurs in the case of bulk states.

Unless otherwise is stated, atomic units are used throughout, i. e., $e^2 = \hbar = m_e = 1$. The atomic unit of length is the Bohr radius, $a_0 = \hbar^2/m_e^2 = 0.529 \text{\AA}$, the atomic unit of energy is the Hartree, 1 Hartree $= e^2/a_0 =$ 27.2 eV, and the atomic unit of velocity is the Bohr velocity, $v_0 = \alpha c = 2.19 \times 10^8 \text{cm s}^{-1}$, α and c being the fine-structure constant and the velocity of light, respectively.

II. ELECTRON-PHONON COUPLING

The decay rate due to the e-ph interaction, which is relatively important only in the case of excited Shockley holes near the Fermi level, has been investigated by using the Eliashberg function [\[32](#page-14-31)]. In particular, at zero temperature $(T = 0)$ and in the high-temperature limit $(k_BT \gg \omega_m, k_B$ being Boltzmann's constant and ω_m , the maximum phonon frequency) one finds respectively, assuming translational invariance in the plane of the surface, the following expressions for the e-ph induced linewidth (or lifetime broadening) Γ_{ep} of surface states of parallel momentum **k** and energy E [\[32](#page-14-31), [33\]](#page-14-32):

$$
\Gamma^{0}_{ep}(\mathbf{k},E) = 2\pi \int_0^{\max(|E|,\omega_m)} \alpha^2 F_{\mathbf{k}}(\omega) d\omega \qquad (1)
$$

and

$$
\Gamma_{ep}(\mathbf{k}, E) = 2\pi \lambda(\mathbf{k}) k_B T,\tag{2}
$$

TABLE I: Electron-phonon linewidths at $T = 0$ (Γ_{ep}^{0}), in meV, and the parameter λ that is responsible for the hightemperature behaviour of Γ_{ep} , as reported at the $\overline{\Gamma}$ point in Refs. [\[34,](#page-14-33) [35](#page-14-34)].

Surface	$\it n$	ep	
$\text{Al}(\overline{100})$		18	0.23
Cu(111)		7.3	0.16
Ag(111)		3.7	0.12
Au(111)	O	3.6	0.11
Cu(100)		< 1 meV	< 0.01
Ag(100)		<1 meV	< 0.01

where $\alpha^2 F_{\mathbf{k}}(\omega)$ is the Eliashberg function, which represents a weighted phonon density of states, and

$$
\lambda(\mathbf{k}) = \int_0^{\omega_m} \frac{\alpha^2 F_{\mathbf{k}}(\omega)}{\omega} d\omega.
$$
 (3)

For many years, the e-ph contribution $\Gamma_{ep}(\mathbf{k}, E)$ to the inelastic decay of surface states had been calculated using a three-dimensional (3D) Debye phonon model with λ obtained from measurements or calculations of bulk properties [\[32\]](#page-14-31). More refined calculations, which are based on an accurate description of the full Eliashberg spectral function, have been carried out recently by Eiguren et al. [\[34,](#page-14-33) [35](#page-14-34)] for (i) the Shockley surface-state hole $(n = 0)$ at the $\overline{\Gamma}$ point of Al(100) and the (111) surfaces of the no-ble metals Cu, Ag, and Au [\[34\]](#page-14-33), and (ii) the first $(n = 1)$ image-state electron at the Γ point of the (100) surfaces of Cu and Ag [\[35\]](#page-14-34); these calculations are based on the use of (i) Thomas-Fermi screened Ashcroft electronion pseudopotentials, (ii) single-particle states obtained by solving a single-particle model one-dimensional (1D) Schrödinger equation, and (iii) a simple force-constant phonon model calculation that yields a phonon spectrum in good agreement with experimental data.

A summary of the results reported by Eiguren et al. [\[34,](#page-14-33) [35](#page-14-34)] is presented in Table [I.](#page-1-0) Electron-phonon linewidths are particularly relevant in the case of surfacestate holes with energies very near the Fermi level, in which case the contribution from e-e interactions is very small. In the case of image states, whose energies lie typically a few electronvolts above the Fermi level, the e-ph linewidth is found to be $\Gamma_{ep} < 1 \,\text{meV}$, thereby showing the negligibly small role of phonons in the electron dynamics of image-potential states.

III. ELECTRON-ELECTRON COUPLING

Let us consider an arbitrary many-electron system of density $n_0(\mathbf{r})$. In the framework of many-body theory, the e-e linewidth (or decay rate) Γ_{ee} of a quasiparticle (electron or hole) that has been added in the singleparticle state $\psi_i(\mathbf{r})$ of energy ε_i is obtained as the projection of the imaginary part of the self-energy $\Sigma(\mathbf{r}, \mathbf{r}'; \varepsilon_i)$

over the quasiparticle-state itself [\[36](#page-15-0), [37](#page-15-1)]:

$$
\Gamma_{ee} = \mp 2 \int d\mathbf{r} \int d\mathbf{r}' \psi_i^*(\mathbf{r}) \mathrm{Im} \Sigma(\mathbf{r}, \mathbf{r}'; \varepsilon_i) \psi_i(\mathbf{r}'), \qquad (4)
$$

where the \mp sign in front of the integral should be taken to be minus or plus depending on whether the quasiparticle is an electron $(\varepsilon_i \geq \varepsilon_F)$ or a hole $(\varepsilon_i \leq \varepsilon_F)$, respectively, ε_F being the Fermi energy. Alternatively, Eq. [\(4\)](#page-2-0) can be written as follows

$$
\Gamma_{ee} = \mp \frac{2}{\pi} \int_{\varepsilon_i - 0^+}^{\varepsilon_i + 0^+} \int d\mathbf{r} \int d\mathbf{r}' g^0(\mathbf{r}, \mathbf{r}'; \varepsilon) \operatorname{Im} \Sigma(\mathbf{r}, \mathbf{r}'; \varepsilon_i),
$$
\n(5)

where

$$
g^{0}(\mathbf{r}, \mathbf{r}'; \varepsilon) = \frac{i}{2} \left\{ G^{0}(\mathbf{r}', \mathbf{r}; \varepsilon) - \left[G^{0}(\mathbf{r}, \mathbf{r}'; \varepsilon) \right]^{*} \right\}, \qquad (6)
$$

 $G^0(\mathbf{r}, \mathbf{r}'; \varepsilon)$ being the one-particle Green function of a noninteracting many-electron system:

$$
G^{0}(\mathbf{r}, \mathbf{r}'; \varepsilon) = \sum_{f} \frac{\psi_{f}(\mathbf{r}) \psi_{f}^{*}(\mathbf{r}')}{\varepsilon - \varepsilon_{f} + i\eta}.
$$
 (7)

Here, $\psi_f(\mathbf{r})$ and ε_f represent the complete set of eigenfunctions and eigenvalues of a one-particle hamiltonian describing the noninteracting many-electron system.

A. Self-energy: G^0W and G^0W^0 approximations

To lowest order in a series-expansion of the selfenergy in terms of the frequency-dependent timeordered screened interaction $W(\mathbf{r}, \mathbf{r}'; \omega)$, the self-energy $\Sigma(\mathbf{r}, \mathbf{r}'; \varepsilon_i)$ is obtained by integrating the product of the interacting Green function $G(\mathbf{r}, \mathbf{r}'; \varepsilon_i - \omega)$ and the screened interaction $W(\mathbf{r}, \mathbf{r}'; \omega)$, and is therefore called the GW self-energy. If one further replaces the interacting Green function by its noninteracting counterpart $G^0(\mathbf{r}, \mathbf{r}'; \varepsilon_i - \omega)$, one finds the G^0W self-energy. For the imaginary part, one can write

$$
\mathrm{Im}\Sigma^{G^0W}(\mathbf{r},\mathbf{r}';\varepsilon_i) = \sum_f{}' \psi_f^*(\mathbf{r}')\mathrm{Im}\,W(\mathbf{r},\mathbf{r}';|\varepsilon_i-\varepsilon_f|)\,\psi_f(\mathbf{r}),\tag{8}
$$

where the prime in the summation indicates that the sum is extended, as in Eq. [\(7\)](#page-2-1), over a complete set of single-particle states $\psi_f(\mathbf{r})$ of energy ε_f but now with the restriction $\varepsilon_F \leq \varepsilon_f \leq \varepsilon_i$ or $\varepsilon_i \leq \varepsilon_f \leq \varepsilon_F$. In terms of the one-particle noninteracting Green function $G^0(\mathbf{r}, \mathbf{r}'; \varepsilon)$, one finds

$$
\mathrm{Im}\Sigma^{G^0W}(\mathbf{r}, \mathbf{r}'; \varepsilon_i) = \frac{1}{\pi} \int_0^{|\varepsilon_i - \varepsilon_F|} d\varepsilon \, \mathrm{Im}g^0(\mathbf{r}, \mathbf{r}'; |\varepsilon_i - \varepsilon|) \times \mathrm{Im} \, W(\mathbf{r}, \mathbf{r}'; \varepsilon), \tag{9}
$$

where $g^0(\mathbf{r}, \mathbf{r}'; \varepsilon)$ is given by Eq. [\(6\)](#page-2-2). Introducing either Eq. (8) or Eq. (9) into Eq. (4) or Eq. (5) , one finds an expression for the e-e linewidth that exactly coincides with the result one would obtain from the lowest-order probability per unit time for an excited electron or hole in an initial state $\psi_i(\mathbf{r})$ of energy ε_i to be scattered into the state $\psi_f(\mathbf{r})$ of energy ε_f by exciting a Fermi system of interacting electrons from its many-particle ground state to some many-particle excited state [\[38\]](#page-15-2).

The screened interaction $W(\mathbf{r}, \mathbf{r}'; \omega)$ entering Eqs. [\(8\)](#page-2-3) and [\(9\)](#page-2-4) can be rigorously expressed as follows

$$
W(\mathbf{r}, \mathbf{r}'; \omega) = v(\mathbf{r}, \mathbf{r}') + \int d\mathbf{r}_1 \int d\mathbf{r}_2 v(\mathbf{r}, \mathbf{r}_1)
$$

$$
\times \chi(\mathbf{r}_1, \mathbf{r}_2; \omega) v(\mathbf{r}_2, \mathbf{r}'), \qquad (10)
$$

 $v(\mathbf{r}, \mathbf{r}')$ representing the bare Coulomb interaction and $\chi(\mathbf{r}, \mathbf{r}'; \omega)$ being the time-ordered density-response function of the many-electron system, which for the positive frequencies ($\omega > 0$) entering Eqs. [\(8\)](#page-2-3) and [\(9\)](#page-2-4) coincides with the retarded density-response function of linearresponse theory. In the framework of time-dependent density-functional theory (TDDFT) [\[39\]](#page-15-3), the exact retarded density-response function is obtained by solving the following integral equation [\[40\]](#page-15-4):

$$
\chi(\mathbf{r}, \mathbf{r}'; \omega) = \chi^0(\mathbf{r}, \mathbf{r}'; \omega) + \int d\mathbf{r}_1 \int d\mathbf{r}_2 \,\chi^0(\mathbf{r}, \mathbf{r}_1; \omega)
$$

$$
\times \{v(\mathbf{r}_1, \mathbf{r}_2) + f^{xc}[n_0](\mathbf{r}_1, \mathbf{r}_2; \omega)\} \,\chi(\mathbf{r}_2, \mathbf{r}'; \omega). \tag{11}
$$

Here, $\chi^0(\mathbf{r}, \mathbf{r}'; \omega)$ denotes the density-response function of noninteracting Kohn-Sham electrons, i.e., independent electrons moving in the effective Kohn-Sham potential of density-functional theory (DFT) [\[41\]](#page-15-5):

$$
\chi^{0}(\mathbf{r}, \mathbf{r}'; \omega) = \frac{2}{\Omega} \sum_{i,j} (f_{i} - f_{j})
$$

$$
\times \frac{\psi_{i}(\mathbf{r}) \psi_{j}^{*}(\mathbf{r}) \psi_{j}(\mathbf{r}') \psi_{i}^{*}(\mathbf{r}')}{\omega - \varepsilon_{j} + \varepsilon_{i} + i\eta}, \qquad (12)
$$

where Ω represents a normalization volume, f_i are Fermi-Dirac occupation factors [which at zero temperature take the form $f_i = \Theta(\varepsilon_F - \varepsilon_i)$, $\Theta(x)$ being the Heaviside step function], and $\psi_i(\mathbf{r})$ and ε_i represent the eigenfunctions and eigenvalues of the Kohn-Sham Hamiltonian of DFT. The other ingredient that is needed in order to solve Eq. [\(11\)](#page-2-6) is the xc kernel $f^{xc}[n_0](\mathbf{r}, \mathbf{r}'; \omega)$, which is the functional derivative of the unknown frequencydependent xc potential $V_{xc}[n](\mathbf{r}, \omega)$ of TDDFT, to be evaluated at $n_0(\mathbf{r})$.

In the random-phase approximation (RPA), $f^{xc}[n_0](\mathbf{r}, \mathbf{r}'; \omega)$ is set equal to zero:

$$
\chi^{RPA}(\mathbf{r}, \mathbf{r}'; \omega) = \chi^{0}(\mathbf{r}, \mathbf{r}'; \omega) + \int d\mathbf{r}_{1} \int d\mathbf{r}_{2} \,\chi^{0}(\mathbf{r}, \mathbf{r}_{1}; \omega) \times v(\mathbf{r}_{1}, \mathbf{r}_{2}) \,\chi^{RPA}(\mathbf{r}_{2}, \mathbf{r}'; \omega),
$$
\n(13)

and the screened interaction $W(\mathbf{r}, \mathbf{r}'; \omega)$ is replaced by

$$
W^{0}(\mathbf{r},\mathbf{r}';\omega) = v(\mathbf{r},\mathbf{r}') + \int d\mathbf{r}_{1} \int d\mathbf{r}_{2} v(\mathbf{r},\mathbf{r}_{1})
$$

$$
\times \ \ \chi^{RPA}(\mathbf{r}_1, \mathbf{r}_2; \omega) \, v(\mathbf{r}_2, \mathbf{r}'), \tag{14}
$$

or, equivalently,

$$
W^{0}(\mathbf{r}, \mathbf{r}'; \omega) = v(\mathbf{r}, \mathbf{r}') + \int d\mathbf{r}_{1} \int d\mathbf{r}_{2} v(\mathbf{r}, \mathbf{r}_{1})
$$

$$
\times \chi^{0}(\mathbf{r}_{1}, \mathbf{r}_{2}; \omega) W^{0}(\mathbf{r}_{2}, \mathbf{r}'; \omega), \qquad (15)
$$

which yields the so-called G^0W^0 (or G^0W -RPA) selfenergy:

$$
\mathrm{Im}\Sigma^{G^0W^0}(\mathbf{r}, \mathbf{r}'; \varepsilon_i) = \sum_f{}' \psi_f^*(\mathbf{r}') \mathrm{Im} \, W^0(\mathbf{r}, \mathbf{r}'; |\varepsilon_i - \varepsilon_f|)
$$

$$
\times \psi_f(\mathbf{r}), \qquad (16)
$$

or, equivalently:

$$
\mathrm{Im}\Sigma^{G^0W^0}(\mathbf{r}, \mathbf{r}'; \varepsilon_i) = \frac{1}{\pi} \int_0^{|\varepsilon_i - \varepsilon_F|} d\varepsilon \mathrm{Im} g^0(\mathbf{r}, \mathbf{r}'; |\varepsilon_i - \varepsilon|) \times \mathrm{Im} W^0(\mathbf{r}, \mathbf{r}'; \varepsilon). \tag{17}
$$

B. Self-energy: GWΓ approach

The xc kernel $f^{xc}[n_0](\mathbf{r}, \mathbf{r}'; \omega)$ entering Eq. [\(11\)](#page-2-6), which is absent in the RPA, accounts for the presence of an xc hole associated to all screening electrons in the Fermi sea. Hence, one might be tempted to conclude that the full G^0W approximation with the formally exact screened interaction W of Eq. (10) should be a better approximation than its G^0W^0 counterpart (with the screened interaction W evaluated in the RPA). However, the xc hole associated to the excited electron (or hole) is still absent in the G^0W approximation. Therefore, if one goes beyond RPA in the description of W , one should also go beyond the G^0W approximation in the expansion of the electron self-energy in powers of W . By including xc effects both beyond RPA in the description of W and beyond G^0W in the description of the self-energy [\[42,](#page-15-6) [43](#page-15-7), [44\]](#page-15-8), the socalled GWΓ approach yields a self-energy that is of the G^0W form:

$$
\mathrm{Im}\Sigma^{GWT}(\mathbf{r}, \mathbf{r}'; \varepsilon_i) = \sum_{f}{}' \psi_f^*(\mathbf{r}') \mathrm{Im}\,\tilde{W}(\mathbf{r}, \mathbf{r}'; |\varepsilon_i - \varepsilon_f|) \,\psi_f(\mathbf{r}),\tag{18}
$$

or, equivalently:

$$
\mathrm{Im}\Sigma^{GWT}(\mathbf{r}, \mathbf{r}'; \varepsilon_i) = \frac{1}{\pi} \int_0^{|\varepsilon_i - \varepsilon_F|} d\varepsilon \mathrm{Im}g^0(\mathbf{r}, \mathbf{r}'; |\varepsilon_i - \varepsilon|) \times \mathrm{Im} \,\tilde{W}(\mathbf{r}, \mathbf{r}'; \varepsilon), \tag{19}
$$

but with the actual screened interaction $W(\mathbf{r}, \mathbf{r}'; \omega)$ entering Eq. [\(8\)](#page-2-3) being replaced by a new effective screened interaction

$$
\tilde{W}(\mathbf{r}, \mathbf{r}'; \omega) = v(\mathbf{r}, \mathbf{r}') + \int d\mathbf{r}_1 \int d\mathbf{r}_2 \, \{v(\mathbf{r}, \mathbf{r}_1) + f^{xc}[n_0](\mathbf{r}, \mathbf{r}_1; \omega)\} \, \chi(\mathbf{r}_1, \mathbf{r}_2; \omega) \, v(\mathbf{r}_2, \mathbf{r}'), \tag{20}
$$

which includes all powers in W beyond the G^0W approximation.

FIG. 2: Probability amplitudes $\phi_n(z)$ and energies ε_n of image-potential-induced bound states $(n = 1, 2, 3)$ outside an infinitely repulsive solid surface occupying the $z < 0$ space (shaded area). The thick solid line represents the classical image potential of Eq. [\(21\)](#page-3-0).

C. Surface-state wave functions

1. Simple models

a. Outside the solid. Image states are quantum states trapped in the long-range image-potential well outside a solid surface that presents a band gap near the vacuum level. In the case of a metal that occupies the half-space $z < 0$, the asymptotic form of the potential experienced by an electron in the half space $z > 0$ is the classical image potential

$$
V(z) = -\frac{1}{4z}.\tag{21}
$$

If one assumes (i) translational invariance in the plane of the surface and (ii) that due to the presence of a wide band gap at $z < 0$ the solid surface is infinitely repulsive, i.e., $V(z) \rightarrow \infty$ at $z < 0$ [\[45\]](#page-15-9), then one easily finds that the solutions of the corresponding one-particle Schrödinger equation represent a Rydberg-like series of image-potential induced bound states (see Fig. [2\)](#page-3-1) of the form:

$$
\psi_{\mathbf{k},n}(\mathbf{r}) = \frac{1}{\sqrt{A}} \phi_n(z) e^{i\mathbf{k} \cdot \mathbf{r}_{\parallel}},
$$
 (22)

with energies

$$
E_{\mathbf{k},n} = \varepsilon_n + \mathbf{k}^2/2,\tag{23}
$$

where

$$
\phi_n(z) \sim z \,\phi_n^{\text{hydrogen}}(z/4), \ n = 1, 2, \dots \tag{24}
$$

and

$$
\varepsilon_n = -\frac{1}{32n^2}, \ n = 1, 2, \dots,
$$
 (25)

 $\phi_n^{\text{hydrogen}}(z)$ representing the well-known wave functions of all possible s-like $(l = 0)$ bound states of the hydrogen atom. Here, \mathbf{r}_{\parallel} and **k** represent the position and the wavevector in the xy surface plane.

FIG. 3: Probability amplitudes $\phi_n(z)$ of (a) Shockley $(n=0)$ and (b) image $(n = 1)$ states on Cu(111). The dotted lines represent the results one obtains by matching at $z = 0$ the wave function of Eqs. [\(26\)](#page-4-0) and [\(27\)](#page-4-1) to a mere exponential (for the Shockley state) or to the hydrogenic form of Eq. [\(24\)](#page-3-2) with $n = 1$ (for the $n = 1$ image state). The solid lines represent the results one obtains by solving a 1D Schrödinger equation with the model potential of Chulkov *et al.* [\[49](#page-15-10)].

b. Inside the solid. In the interior of the solid $(z <$ 0), both image and Shockley surface states can be described within a two-band approximation to the nearlyfree-electron (NFE) band structure of the solid [\[46\]](#page-15-11). Assuming translational invariance in the plane of the surface and for a gap that is opened by potential Fourier components corresponding to reciprocal lattice vectors that are normal to the surface, surface-state wave functions within the crystal band gap take the form

$$
\phi(z<0) \approx e^{\Delta} \cos(Gz+\delta). \tag{26}
$$

Here, G represents the limit of the Brillouin zone in the direction normal to the surface, and

$$
\Delta = \frac{1}{G} \sqrt{\frac{1}{4} V_g^2 - \bar{\varepsilon}^2},\tag{27}
$$

where V_g and $\bar{\varepsilon}$ denote the energy gap and the surfacestate energy with respect to the mid gap, respectively, and δ represents a phase shift which in the presence of a Shockley-inverted band gap [\[47\]](#page-15-12) varies from $-\pi/2$ for a surface-state energy ε at the bottom of the gap to 0 for a surface-state energy at the top of the gap. Matching at $z = 0$ to a wave function of the hydrogenic-like form of Eq. [\(24\)](#page-3-2) (in the case of image states) or to a mere exponential (in the case of Shockley states) [\[48\]](#page-15-13), one finds the wave functions $\phi_n(z)$ plotted by dotted lines in Fig. [3](#page-4-2) for $Cu(111)$.

2. One-dimensional model potentials

Still assuming translational invariance in two directions, i.e., assuming that the charge density and oneelectron potential are constant in the plane of the surface,

Chulkov et al. [\[49\]](#page-15-10) devised a simplified model that allows for realistic calculations while retaining at the same time the essential physics of electron and hole dynamics at solid surfaces. In the bulk region, this one-dimensional (1D) model potential is described by a cosine function which opens the energy gap on the surface of interest, the position and amplitude of this function being chosen to reproduce the energy gap observed experimentally and/or obtained from first-principles calculations at the $\bar{\Gamma}$ point. At the solid-vacuum interface, it is represented by a smooth cosine-like function that reproduces the experimental energy of the Shockley surface state. Finally, in the vacuum region this 1D potential merges into the long-range classical image potential of the form of Eq. [\(21\)](#page-3-0) in such a way that the experimental binding energy of the first image state is reproduced. This model potential has been constructuted for several metal surfaces [\[50\]](#page-15-14), and has been used widely for the investigation of electron and hole dynamics in a variety of situations.

The $n = 0$ and $n = 1$ eigenfunctions of a singleparticle 1D hamiltonian that includes the model potential of Chulkov *et al.* for $Cu(111)$ are plotted in Fig. [3](#page-4-2) by solid lines, together with the NFE Shockley $(n = 0)$ and first image-state $(n = 1)$ wave functions described in the preceding section. In the bulk region, these wave functions coincide with the approximate NFE wave functions (represented in Fig. [3](#page-4-2) by dotted lines); however, in the vacuum region the $n = 1$ hydrogenic-like wave function of Eq. [\(24\)](#page-3-2) appears to be too little localized near the surface. The $n = 1$ eigenfunction of Chulkov's 1D hamiltonian for $Cu(100)$ [\[51\]](#page-15-15) was found to reproduce accurately the average probability density derived for that image state by Hulbert et al. [\[52](#page-15-16)] from a first-principles calculation.

The assumption that the charge density and oneelectron potential are constant in the plane of the surface is valid for the description of image states, since their wave functions lie mainly at the vacuum side of the surface and the electrons move, therefore, in a region with little potential variation parallel to the surface. Shockley and bulk states, however, do suffer a significant potential variation in the plane of the surface. In order to account approximately for this variation, the original 1D model potential of Chulkov et al. [\[49\]](#page-15-10), which had been introduced to describe the projected band structure at the $\overline{\Gamma}$ point, was modified along with the introduction in Eq. [\(23\)](#page-3-3) of a realistic effective mass for the dispersion curve of both bulk and surface states [\[48\]](#page-15-13). Within this model, however, all Shockley states have the same effective mass, so the projected band structure is still inaccurate, especially at energies above the Fermi level, as shown in Fig. [4](#page-5-0) for $Cu(111)$.

As an alternative to the 1D model potential of Chulkov et al. [\[49](#page-15-10)], Vergniory et al. [\[53](#page-15-17)] introduced a k-dependent 1D potential that is constructed to reproduce the actual bulk energy bands and surface-state energy dispersion obtained from 3D first-principles calculations, thereby allowing for a realistic description of the electronic orbitals

FIG. 4: Dispersion of the Cu(111) Shockley surface state (thick solid line), as obtained from 3D *ab initio* calculations [\[53\]](#page-15-17). Shaded areas represent areas outside the band gap, where bulk states exist. The thin solid and dotted lines represent approximate energy dispersions of the Shockley surface state and the bottom of the projected band gap, respectively, as obtained from an equation of the form of Eq. [\(23\)](#page-3-3) with the Cu(111) $\bar{\Gamma}$ -point Shockley-state energy (with respect to the Fermi level) $\varepsilon = -0.44 \text{ eV}$ and the effective mass $m = 0.42$ (thin solid line), and with the Cu(111) $\bar{\Gamma}$ -point bottom-of-thegap energy (with respect to the Fermi level) $\varepsilon = -1.09 \text{ eV}$ and the effective mass $m = 0.22$ (thin dotted line).

beyond the $\overline{\Gamma}$ point:

$$
V_k(z) = \begin{cases} U_k + 2V_k \cos(2\pi z/a_s), & z < z_k \\ \Phi & z > z_k. \end{cases} \tag{28}
$$

Here, U_k and V_k are fitted to the bulk energy bands, a_s represents the interlayer spacing, Φ is the experimentally determined work function, and the matching plane z_k is chosen to give the correct surface-state dispersion.

The abrupt 1D step model potential of Eq. [\(28\)](#page-5-1), which does not account for the image tail outside the surface, could not possibly be used to describe image states. However, it has proved to be accurate for the description of Shockley surface states, which are known to be rather insensitive to the actual shape of the potential far outside the surface; indeed, the model potential of Eq. [\(28\)](#page-5-1) is found to yield a surface-state probability density $|\phi(z)|^2$ at the band edge ($\overline{\Gamma}$ point, i.e., $\mathbf{k} = 0$) of the Shockley surface-state band of $Cu(111)$ that is in reasonably good agreement with the more realistic surface-state probability density obtained at $\overline{\Gamma}$ from the 1D model potential of Chulkov et al. [\[49](#page-15-10)], as shown in Fig. [5.](#page-5-2) Both probability densities coincide within the bulk, although the probability density obtained from the step model potential of Eq. [\(28\)](#page-5-1) appears to be slightly more localized near the surface, as expected. For the overlap integral one finds $<\phi_1|\phi_2>=0.99$, ϕ_1 and ϕ_2 being the Shockley probability amplitudes leading to the probability densities represented in Fig. [5](#page-5-2) by solid and dashed lines, respectively.

FIG. 5: Probability-density $|\phi(z)|^2$ of the Shockley surface state at the center of the surface Brillouin zone ($\overline{\Gamma}$ point) of Cu(111), as obtained with the use of two different 1D model potentials: (i) the model potential of Chulkov *et al.* [\[49](#page-15-10)], which includes the image tail outside the surface but fails to reproduce the actual band structure beyond the $\bar{\Gamma}$ point (solid line), and (ii) the model potential of Eq. [\(28\)](#page-5-1), which does not include the image tail outside the surface but is constructed to reproduce the actual bulk energy bands and surface-state energy dispersion beyond the $\bar{\Gamma}$ point (dashed line). Full circles represent the atomic positions of Cu in the (111) direction. The geometrical (jellium) electronic edge $(z = 0)$ has been chosen to be located half an interlayer spacing beyond the last atomic layer.

D. Screened interaction

The retarded counterpart of the density-response function entering Eq. [\(10\)](#page-2-7), which in the framework of TDDFT can be obtained rigorously by solving the intergral Eq. [\(11\)](#page-2-6), yields, within linear-response theory, the electron density $\delta n(\mathbf{r}, \omega)$ induced in a many-electron system by a frequency-dependent external potential $\phi^{ext}(\mathbf{r}, \omega)$:

$$
\delta n(\mathbf{r}, \omega) = \int \mathrm{d}\mathbf{r}' \, \chi(\mathbf{r}, \mathbf{r}'; \omega) \, \phi^{ext}(\mathbf{r}', \omega). \tag{29}
$$

Hence, the retarded counterpart of the screened interaction $W(\mathbf{r}, \mathbf{r}'; \omega)$ of Eq. [\(10\)](#page-2-7) yields, within linear-response theory, the total potential $\phi(\mathbf{r}, \omega)$ of a unit test charge at point r in the presence of an external test charge of density $n^{ext}(\mathbf{r}, \omega)$:

$$
\phi(\mathbf{r}, \omega) = \int d\mathbf{r}' W(\mathbf{r}, \mathbf{r}'; \omega) n^{ext}(\mathbf{r}', \omega), \quad (30)
$$

which can also be expressed as follows

$$
\phi(\mathbf{r}, \omega) = \int d\mathbf{r}' \, \epsilon^{-1}(\mathbf{r}, \mathbf{r}'; \omega) \, \phi^{ext}(\mathbf{r}, \omega), \qquad (31)
$$

with

$$
\epsilon^{-1}(\mathbf{r}, \mathbf{r}'; \omega) = \delta(\mathbf{r} - \mathbf{r}') + \int d\mathbf{r}'' \, v(\mathbf{r} - \mathbf{r}'') \, \chi(\mathbf{r}'', \mathbf{r}'; \omega).
$$
\n(32)

This is the so-called inverse dielectric function of the many-electron system, whose poles dictate the occurrence of collective electronic excitations.

1. Classical model

In a classical model consisting of a semiinfinite solid at $z < 0$ characterized by a local (frequency-dependent) dielectric function $\epsilon(\omega)$ separated by a planar surface from a semiinfinite vacuum at $z > 0$, the total potential $\phi(\mathbf{r}, \omega)$ at each medium is a solution of Poisson's equation

$$
\nabla^2 \phi(\mathbf{r}, \omega) = -\frac{4\pi}{\epsilon_i(\omega)} n^{ext}(\mathbf{r}, \omega), \tag{33}
$$

 ϵ_i being $\epsilon(\omega)$ or 1 depending on whether the point **r** is located in the solid or in the vacuum, respectively. Hence,

the screened interaction $W(\mathbf{r}, \mathbf{r}'; \omega)$ entering Eq. [\(30\)](#page-5-3) is a solution of the following equation:

$$
\nabla^2 W(\mathbf{r}, \mathbf{r}'; \omega) = -\frac{4\pi}{\epsilon_i(\omega)} \delta(\mathbf{r} - \mathbf{r}'). \tag{34}
$$

Imposing boundary conditions of continuity of the potential and the normal component of the displacement vector at the interface, one finds

$$
W(\mathbf{r}, \mathbf{r}'; \omega) = \int d\mathbf{q} e^{i\mathbf{q} \cdot (\mathbf{r}_{\parallel} - \mathbf{r}'_{\parallel})} W(z, z'; q, \omega), \qquad (35)
$$

where

$$
W(z, z'; q, \omega) = \frac{2\pi}{q} \begin{cases} \left[e^{-q|z-z'|} + g(\omega) e^{-q(|z|+z'|)} \right] / \epsilon(\omega), & z < 0, z' < 0, \\ 2 \, g(\omega) \, e^{-qz-z'|} / \left[\epsilon(\omega) - 1 \right], & z^{\leq} < 0, z^{\geq} > 0, \\ 2 \, e^{-q|z-z'|} - g(\omega) \, e^{-q(|z|+|z'|)}, & z > 0, z' > 0, \end{cases} \tag{36}
$$

 $z⁰(z⁰)$ being the smallest (largest) of z and z', and g being the classical surface-response function:

$$
g(\omega) = \frac{\epsilon(\omega) - 1}{\epsilon(\omega) + 1}.
$$
 (37)

An inspection of Eqs. [\(36\)](#page-6-0) and [\(37\)](#page-6-1) shows that the screened interaction $W(z, z'; q, \omega)$ has poles at the *clas*sical bulk- and surface-plasmon conditions dictated by $\epsilon(\omega) = 0$ and by $\epsilon(\omega) + 1 = 0$, respectively [\[54](#page-15-18)]. Since e-e inelastic linewidths of Shockley and image states are typically dominated by the excitation of electron-hole (e-h) pairs and not by the excitation of plasmons (whose energies are typically too large) [\[55\]](#page-15-19), the classical screened interaction of Eq. [\(36\)](#page-6-0) (which obviously does not account for the excitation of e-h pairs) is of no use in this context.

A simple scheme that gives account of the excitation of e-h pairs, and has the virtue of expressing the screened interaction $W(z, z'; q, \omega)$ in terms of the dielectric function $\epsilon(q,\omega)$ of a homogeneous electron gas representing the bulk material, is the so-called specular-reflection model reported independently by Wagner [\[57\]](#page-15-20) and by Ritchie and Marusak [\[58\]](#page-15-21). In this model, the semi-infinite solid is described by an electron gas in which all electrons are considered to be specularly reflected at the surface, thereby the electron density vanishing outside. One finds:

$$
W(z, z'; q, \omega) = \frac{2\pi}{q} \begin{cases} \epsilon_s(z - z') + \epsilon_s(z + z') - 2g(q, \omega) \frac{\epsilon_s(z) \epsilon_s(z')}{1 - \epsilon_s^0}, & z < 0, z' < 0, \\ 2g(q, \omega) \frac{\epsilon_s(z')}{1 - \epsilon_s^0} e^{-qz^>}, & z < 0, z^> > 0, \\ e^{-q|z - z'|} - g(q, \omega) e^{-q(z + z')}, & z > 0, z' > 0, \end{cases}
$$
(38)

where the surface response function is now given by the following expression:

with

$$
\epsilon_s(z;q,\omega) = \frac{q}{\pi} \int_{-\infty}^{+\infty} \frac{dq_z}{Q^2} e^{iq_z z} \epsilon^{-1}(Q,\omega), \tag{40}
$$

$$
g(q,\omega) = \frac{1 - \epsilon_s^0(q,\omega)}{1 + \epsilon_s^0(q,\omega)},
$$
\n(39)

^{2.} Specular-reflection model (SRM)

$$
\epsilon_s^0(q,\omega) = \epsilon_s(z=0;q,\omega),\tag{41}
$$

and $Q = \sqrt{q^2 + q_z^2}$. If the Q-dependence of the actual $\epsilon(Q, \omega)$ dielectric function of a homogeneous electron gas is ignored, the SRM screened interaction of Eq. [\(38\)](#page-6-2) reduces to the classical screened interaction of Eq. [\(36\)](#page-6-0).

The inverse dielectric function $\epsilon^{-1}(Q,\omega)$ entering Eq. [\(40\)](#page-6-3) represents the 3D Fourier transform of the inverse dielectric function $\epsilon^{-1}(\mathbf{r}, \mathbf{r}', \omega)$ of a homogeneous electron gas. From Eq. [\(32\)](#page-5-4), one finds:

$$
\epsilon^{-1}(Q,\omega) = 1 + v_Q \chi(Q,\omega),\tag{42}
$$

where $\chi(Q,\omega)$ represents the 3D Fourier transform of the density-response function $\chi(\mathbf{r}, \mathbf{r}'; \omega)$, and v_Q is the 3D Fourier transform of the bare Coulomb interaction $v(\mathbf{r}, \mathbf{r}')$: $v_Q = 4\pi/Q^2$.

In the framework of TDDFT, one uses Eq. [\(11\)](#page-2-6) to find

$$
\chi(Q,\omega) = \chi^0(Q,\omega) + \chi^0(Q,\omega)
$$

$$
\times \{v_Q + f^{xc}(n_0;Q,\omega)\} \chi(Q,\omega),
$$
 (43)

with $\chi^0(Q,\omega)$ and $f^{xc}(n_0;Q,\omega)$ being the 3D Fourier transforms of the noninteracting density-response function $\chi^0(\mathbf{r}, \mathbf{r}'; \omega)$ and the xc kernel $f^{xc}[n_0](\mathbf{r}, \mathbf{r}'; \omega)$ of a homogeneous electron gas of density n_0 . For a homogeneous electron gas, the eigenfunctions $\psi_i(\mathbf{r})$ entering Eq. [\(12\)](#page-2-8) are all plane waves; thus, the integrations can be carried out analytically to yield the well-known Lindhard function $\chi^0(Q,\omega)$ [\[59\]](#page-15-22). If one sets the xc kernel $f^{xc}(n_0; Q, \omega)$ equal to zero, the introduction of Eq. [\(43\)](#page-7-0) into Eq. [\(42\)](#page-7-1) yields the RPA dielectric function

$$
\epsilon^{RPA}(Q,\omega) = 1 - v_Q \chi^0(Q,\omega),\tag{44}
$$

which is easy to evaluate.

3. 1D self-consistent scheme

For an accurate quantal description of the electronic excitations that occur in a semi-infinite solid, we need to consider the true self-consistent density-response function $\chi(\mathbf{r}, \mathbf{r}'; \omega)$ entering Eqs. [\(10\)](#page-2-7) and [\(20\)](#page-3-4).

Assuming translational invariance in the plane of the surface, one can still define the 2D Fourier transforms $W(z, z'; q, \omega)$ and $\tilde{W}(z, z'; q, \omega)$, which according to Eqs. [\(10\)](#page-2-7) and [\(20\)](#page-3-4) can be obtained as follows

$$
W(z, z'; q, \omega) = v(z, z'; q) + \int dz_1 \int dz_2 v(z, z_1; q)
$$

$$
\times \chi(z_1, z_2; q, \omega) v(z_2, z'; q),
$$
 (45)

and

$$
\tilde{W}(z, z'; q, \omega) = v(z, z'; q) + \int dz_1 \int dz_2 \ \{v(z, z_1; q)
$$
\n
$$
+ f^{xc}[n_0](z, z_1; q, \omega) \} \ \chi(z_1, z_2; q, \omega) \ v(z_2, z', q), \quad (46)
$$

where $v(z, z'; q)$ is the 2D Fourier transform of the bare Coulomb interaction $v(\mathbf{r}, \mathbf{r}')$:

$$
v(z, z'; q) = \frac{2\pi}{q} e^{-q|z - z'|},
$$
\n(47)

 $f^{xc}[n](z, z'; q, \omega)$ is the 2D Fourier transform of the xc kernel $f^{xc}[n](\mathbf{r}, \mathbf{r}'; \omega)$, and $\chi(z, z'; q, \omega)$ denotes the 2D Fourier transform of the interacting density-response function $\chi(\mathbf{r}, \mathbf{r}'; \omega)$. In the framework of TDDFT, one uses Eq. (11) to find:

$$
\chi(z, z'; q, \omega) = \chi^{0}(z, z'; q, \omega) + \int dz_{1} \int dz_{2} \chi^{0}(z, z_{1}; q, \omega)
$$

$$
\times \{v(z_{1}, z_{2}; q) + f^{xc}[n_{0}](z_{1}, z_{2}; q, \omega)\} \chi(z_{2}, z'; q, \omega), \quad (48)
$$

where $\chi^0(z, z'; q, \omega)$ denotes the 2D Fourier transform of the noninteracting density-response function $\chi^0(\mathbf{r}, \mathbf{r}'; \omega)$. Using Eq. [\(12\)](#page-2-8), and noting that the single-particle orbitals $\psi_i(\mathbf{r})$ now take the form

$$
\psi_{\mathbf{k},i}(\mathbf{r}) = \phi_i(z) e^{i\mathbf{k}\cdot\mathbf{r}_{\parallel}},\tag{49}
$$

one finds:

$$
\chi^{0}(z, z'; q, \omega) = \frac{2}{A} \sum_{i,j} \phi_{i}(z) \phi_{j}^{*}(z) \phi_{j}(z') \phi_{i}^{*}(z')
$$

$$
\times \sum_{\mathbf{k}} \frac{f_{\mathbf{k},i} - f_{\mathbf{k} + \mathbf{q},j}}{E_{\mathbf{k},i} - E_{\mathbf{k} + \mathbf{q},j} + \omega + i\eta},
$$
(50)

where $f_{\mathbf{k},i}$ are Fermi-Dirac occupation factors [which at zero temperature take the form $f_{\mathbf{k},i} = \Theta(\varepsilon_F - E_{\mathbf{k},i})$, and

$$
E_{\mathbf{k},i} = \varepsilon_i + \frac{k^2}{2},\tag{51}
$$

the single-particle orbitals $\phi_i(z)$ and energies ε_i now being the eigenfunctions and eigenenergies of a 1D Kohn-Sham hamiltonian. In order to account for the actual band structure of sp electrons near the surface of simple and noble metals, $\phi_i(z)$ and ε_i have been succesfully taken to be the solutions of the 1D single-particle Schrödinger equation of Chulkov et al. [\[49\]](#page-15-10) described in the previous section.

4. Asymptotics

For z and z' coordinates that are far from the surface into the vacuum, where the electron density vanishes, Eq. (45) takes the form $[60]$

$$
W(z, z'; q, \omega) = v(z, z'; q) - \frac{2\pi}{q} e^{-q(z+z')} g(q, \omega), \quad (52)
$$

with the surface-response function $g(q,\omega)$ now being given by the general expression [\[61](#page-15-24)]:

$$
g(q,\omega) = -\frac{2\pi}{q} \int dz_1 \int dz_2 e^{q(z_1+z_2)} \chi(z_1, z_2; q, \omega).
$$
\n(53)

Persson and Anderson [\[62](#page-15-25)] and Persson and Zaremba [\[63](#page-15-26)] investigated the structure of the socalled surface loss function $\text{Im} q(q,\omega)$ for small q and ω . Persson and Zaremba found the following approximate result [\[63\]](#page-15-26):

$$
\operatorname{Im} g = (\operatorname{Im} g)_{surf} + (\operatorname{Im} g)_{bulk} + (\operatorname{Im} g)_{int}, \tag{54}
$$

where $(\text{Im } g)_{surf}$ and $(\text{Im } g)_{bulk}$ represent contributions from surface and bulk excitation of e-h pairs, and $(\text{Im } g)_{int}$ represents the contribution to the surface loss function coming from the interference between the bulk and surface excitations:

$$
(\mathrm{Im}\,g)_{surf} = 2\xi \frac{q}{k_F} \frac{\omega}{\omega_p},\tag{55}
$$

$$
(\text{Im } g)_{bulk} = \frac{1}{2} m_{opt}^2 \left(\frac{\omega}{\omega_p}\right)^2 \eta^3 G(\eta), \tag{56}
$$

and

$$
(\text{Im } g)_{int} = -\frac{8}{\pi^2} \frac{m_{opt}}{k_F} \left(\frac{\omega}{\omega_p}\right)^2 \eta \frac{h}{1 + \eta^2},\qquad(57)
$$

with $\eta = \omega/(q k_F)$ and

$$
G(\eta) = 8 \begin{cases} 1, & \text{for } \eta < 1, \\ 1 - (1 + \frac{1}{2}\eta^{-2})(1 - \eta^{-2})^{1/2}, & \text{for } \eta > 1. \end{cases}
$$
(58)

Here, k_F and ω_p represent the Fermi momentum and the plasmon frequency, respectively: $k_F^3 = 3\pi^2 \bar{n}_0$ and $\omega_p^2 = 4\pi \bar{n}_0$, \bar{n}_0 being the mean electron density. The values of ξ , m_{opt} , and h are given in Ref. [\[63\]](#page-15-26). The surface contribution of Eq. [\(55\)](#page-8-0) had already been reported in Ref. [\[62](#page-15-25)], the bulk contribution of Eq. [\(56\)](#page-8-1) differs from that used in Ref. [\[62](#page-15-25)] by the factor of the optical mass and a factor of $\frac{1}{2}$ which had been missed previously, and the contribution $(\text{Im } g)_{int}$ had been neglected in Ref. [\[62\]](#page-15-25).

5. The xc kernel $f^{xc}[n](z, z'; q, \omega)$

Several approximations can be used to evaluate the unknown xc kernel $f^{xc}[n_0](z, z'; q, \omega)$ entering Eqs. [\(46\)](#page-7-3) and [\(48\)](#page-7-4).

a. Random-phase approximation (RPA). Nowadays one usually refers to the RPA as the result of simply setting the xc kernel $f^{xc}[n](z, z'; q, \omega)$ equal to zero: $f^{xc}[n](z, z'; q, \omega) = 0$, but still using in Eqs. [\(49\)](#page-7-5) and [\(51\)](#page-7-6) single-particle Kohn-Sham states and energies $\phi_i(z)$ and ε_i that go beyond the Hartree approximation.

b. Adiabatic local-density approximation (ALDA). If one assumes that dynamic electron-density fluctuations are slowly varying in all directions, the xc kernel $f^{xc}[n](z, z'; q, \omega)$ is easily found to be given by the following expression [\[61](#page-15-24)]:

$$
f^{xc}[n](z, z'; q, \omega) = \bar{f}^{xc}(n = n(z); Q = 0, \omega = 0) \,\delta(z - z').
$$
\n(59)

Here, $\bar{f}^{xc}(n=n(z);Q,\omega)$ is the 3D Fourier transform of the xc kernel of a homogeneous electron gas of density n equal to the local density $n(z)$, which in the limit as $Q \rightarrow 0$ and $\omega \rightarrow 0$ is known to be the second derivative of the xc energy per particle $\varepsilon_{xc}(n)$. One typically uses parametrizations [\[64\]](#page-15-27) of the diffusion Monte Carlo (DMC) xc energy ε_{xc} reported by Ceperley and Alder [\[65](#page-15-28)].

c. Adiabatic nonlocal approximation (ANLDA). The investigation of short-range xc effects in solids has focused to a great extent onto the homogeneous electron gas [\[66\]](#page-15-29). Hence, assuming that the unperturbed density variation $[n(z) - n(z')]$ is small within the short range of $f^{xc}[n](z, z'; q, \omega)$, one can adopt the following average adiabatic nonlocal approximation [\[67,](#page-15-30) [68,](#page-15-31) [69\]](#page-15-32):

$$
f^{xc}[n](z, z'; q, \omega) = \bar{f}^{xc}([n(z) + n(z')] / 2; z, z'; q, \omega = 0),
$$
\n(60)

where $\bar{f}^{xc}(n; z, z'; q, \omega)$ represents the 1D Fourier transform of the xc kernel $\hat{f}^{xc}(n; Q, \omega)$ of a homogeneous electron gas of density n. A parametrization of the accurate DMC calculations reported by Moroni et al. [\[70](#page-15-33)] for the static $(\omega = 0)$ Q-dependent nonlocal xc kernel $\bar{f}^{xc}(n; Q, \omega = 0)$ that satisfies the well-known small and large-wavelength asymptotic behaviour was carried out by Corradini et al. (CDOP) [\[71\]](#page-15-34). An explicit expression for the 2D Fourier transform of the CDOP parametrization of $\bar{f}^{xc}(n; Q, \omega = 0)$ was reported in Ref. [\[69\]](#page-15-32):

$$
\bar{f}^{xc}(n; z, z'; k) = -\frac{4\pi e^2 C}{k_F^2} \delta(\tilde{z}) - \frac{2\pi e^2 B}{\sqrt{g k_F^2 + k^2}} e^{-\sqrt{g k_F^2 + k^2} |\tilde{z}|} - \frac{2\alpha \sqrt{\pi/\beta} e^2}{k_F^3} \left[\frac{2\beta - k_F^2 \tilde{z}^2}{4\beta^2} k_F^2 + k^2 \right] e^{-\beta \left[k_F^2 \tilde{z}^2 / 4\beta^2 + k^2 / k_F^2\right]},
$$
\n(61)

where C, B, g, α , and β are dimensionless functions of the electron density (see Ref. [\[71](#page-15-34)]), $k_F = (3\pi^2 n)^{1/3}$, and

 $\tilde{z}=z-z^{\prime}$.

Calculations of the frequency dependence of the xc kernel of a homogeneous electron gas have been carried out mainly in the limit of long wavelengths [\[72,](#page-15-35) [73,](#page-15-36) [74](#page-15-37), [75](#page-15-38), [76,](#page-15-39) [77](#page-15-40)], but work has also been done for finite wave vectors [\[78,](#page-15-41) [79,](#page-15-42) [80](#page-15-43), [81\]](#page-15-44). Approximate expressions for the frequency-dependent xc kernel of inhomogeneous systems have been reported in Refs. [\[82,](#page-15-45) [83,](#page-15-46) [84,](#page-15-47) [85\]](#page-15-48).

6. d−*electron screening*

The 1D self-consistent scheme described above has proved to be appropriate for the description of the screened interaction of sp electrons in simple and noble metals. It has been argued, however, in the past that a realistic first-principles description of the electronic band structure is of key importance in the determination of the inelastic lifetime of bulk electronic states in the noble metals, due to the participation of d electrons in the screening of e-e interactions [\[86\]](#page-15-49).

Following the scheme originally developed by Liebsch to describe the anomalous dispersion of surface plasmons in Ag [\[87](#page-15-50)], García-Lekue *et al.* [\[56\]](#page-15-51) accounted for the presence of occupied d-bands in the noble metals by assuming that sp valence electrons are embedded in a polarizable background at $z \leq z_0$ characterized by a local dielectric function $\epsilon_d(\omega)$. Within this model, the bare Coulomb interaction $v(z, z'; q)$ entering Eq. [\(48\)](#page-7-4) is replaced by a modified (*d*-screened) Coulomb interaction $v'(z, z'; q, \omega)$ whose 2D Fourier transform yields [\[88](#page-15-52)]

$$
v'(z, z'; q, \omega) = \frac{2\pi}{q \epsilon_d(z', \omega)} [e^{-q |z - z'|} + sgn(z_d - z') \times \sigma_d(\omega) e^{-q |z - z_d|} e^{-q |z_d - z'|}],
$$
(62)

where

$$
\epsilon_d(z,\omega) = \begin{cases} \epsilon_d(\omega), & z \le z_d \\ 1, & z > z_d \end{cases}
$$
 (63)

and

$$
\sigma_d = \frac{\epsilon_d(\omega) - 1}{\epsilon_d(\omega) + 1}.\tag{64}
$$

The first term in Eq. [\(62\)](#page-9-0) is simply the 2D Fourier transform of the bare Coulomb interaction [see Eq. [\(47\)](#page-7-7)], but now screened by the polarization charges induced within the polarizable background. The second term stems from polarization charges at the boundary of the medium.

7. Periodic surface

For a real periodic surface, one may introduce the following Fourier expansion of the screened interaction:

$$
W(\mathbf{r}, \mathbf{r}'; \omega) = \frac{1}{A} \sum_{\mathbf{q}}^{SBZ} \sum_{\mathbf{g}, \mathbf{g}'} e^{i(\mathbf{q} + \mathbf{g}) \cdot \mathbf{r}_{\parallel}} e^{-i(\mathbf{q} + \mathbf{g}') \cdot \mathbf{r}_{\parallel}'}
$$

$$
\times \ W_{\mathbf{g},\mathbf{g}'}(z,z';\mathbf{q},\omega),\tag{65}
$$

where **q** is a 2D wave vector in the surface Brillouin zone (SBZ), and g and g ′ denote 2D reciprocal-lattice vectors. According to Eq. [\(10\)](#page-2-7), the 2D Fourier coefficients $W_{g,g'}(z, z'; \mathbf{q}, \omega)$ are given by the following expression:

$$
W_{\mathbf{g},\mathbf{g}'}(z,z';\mathbf{q},\omega) = v_{\mathbf{g}}(z,z';\mathbf{q}) \, \delta_{\mathbf{g},\mathbf{g}'} + \int dz_1 \int dz_2
$$

$$
\times v_{\mathbf{g}}(z,z_1;\mathbf{q}) \, \chi_{\mathbf{g},\mathbf{g}'}(z_1,z_2;\mathbf{q},\omega) \, v_{\mathbf{g}'}(z_2,z';\mathbf{q}), \qquad (66)
$$

where $v_{\mathbf{g}}(z, z'; \mathbf{q})$ denote the 2D Fourier coefficients of the bare Coulomb interaction $v(\mathbf{r}, \mathbf{r}')$:

$$
v_{\mathbf{g}}(z, z'; \mathbf{q}) = \frac{2\pi}{|\mathbf{q} + \mathbf{g}|} e^{-|\mathbf{q} + \mathbf{g}| |z - z'|},\tag{67}
$$

and $\chi_{\mathbf{g},\mathbf{g}'}(z,z';\mathbf{q},\omega)$ are the Fourier coefficients of the interacting density-response function $\chi(\mathbf{r}, \mathbf{r}'; \omega)$. In the framework of TDDFT, one uses Eq. [\(11\)](#page-2-6) to find:

$$
\chi_{\mathbf{g},\mathbf{g}'}(z,z';\mathbf{q},\omega) = \chi_{\mathbf{g},\mathbf{g}'}^0(z,z';\mathbf{q},\omega) + \int dz_1 \int dz_2
$$

\n
$$
\times \chi_{\mathbf{g},\mathbf{g}'}^0(z,z_1;\mathbf{q},\omega) \times [v_{\mathbf{g}_1}(z_1,z_2;\mathbf{q}) \delta_{\mathbf{g}_1,\mathbf{g}_2}
$$

\n
$$
+ f_{\mathbf{g}_1,\mathbf{g}_2}^{xc}[n_0](z_1,z_2;\mathbf{q},\omega)] \chi_{\mathbf{g}_2,\mathbf{g}'}(z_2,z';\mathbf{q},\omega), \qquad (68)
$$

where $\chi^0_{g,g'}(z,z';q,\omega)$ and $f^{xc}_{g,g'}[n_0](z,z';q,\omega)$ denote the Fourier coefficients of the noninteracting densityresponse function $\chi^0(\mathbf{r}, \mathbf{r}'; \omega)$ and the xc kernel $f^{xc}[n_0](\mathbf{r}, \mathbf{r}'; \omega)$, respectively. Using Eq. [\(12\)](#page-2-8), one finds:

$$
\chi_{\mathbf{g},\mathbf{g}'}^{0}(z,z';\mathbf{q},\omega) = \frac{2}{A} \sum_{\mathbf{k}}^{S B Z} \sum_{n,n'} \frac{f_{\mathbf{k},n} - f_{\mathbf{k}+\mathbf{q},n'}}{\varepsilon_{\mathbf{k},n} - \varepsilon_{\mathbf{k}+\mathbf{q},n'} + \omega + i\eta}
$$

$$
\times \left\langle \phi_{\mathbf{k},n}(z) | e^{-i(\mathbf{q}+\mathbf{g}) \cdot \mathbf{r}_{\parallel}} | \phi_{\mathbf{k}+\mathbf{q},n'}(z') \right\rangle
$$

$$
\times \left\langle \phi_{\mathbf{k}+\mathbf{q},n'}(z') | e^{i(\mathbf{q}+\mathbf{g}') \cdot \mathbf{r}_{\parallel}} | \phi_{\mathbf{k},n}(z) \right\rangle, \tag{69}
$$

the single-particle orbitals $\phi_{\mathbf{k},n}(\mathbf{r})$ and energies $\varepsilon_{\mathbf{k},n}$ being the eigenfunctions and eigenvalues of a 3D Kohn-Sham Hamiltonian with an effective potential that is periodic in the plane of the surface.

IV. RESULTS AND DISCUSSION

A. Image states

The first quantitative evaluation of image-state lifetimes was reported in Ref. [\[89\]](#page-15-53). This calculation was carried out from Eqs. [\(4\)](#page-2-0) and [\(8\)](#page-2-3), with (i) the hydrogeniclike image-state wave function $\phi_i(z)$ of Eq. [\(24\)](#page-3-2) with $n = 1$ and no penetration into the solid, (ii) the bulk final state wave functions $\phi_f(z)$ obtained with the use of a step model potential, and (iii) two simplified models for the screened interaction: the SRM of Eq. [\(38\)](#page-6-2) with the

RPA for the bulk dielectric function, and the surface response function reported by Persson and Anderson [\[62\]](#page-15-25). In subsequent calculations the penetration of the imagestate wave function into the crystal was allowed [\[90\]](#page-15-54), and the role that the unoccupied part of the narrow Shockley surface state on the (111) surfaces of Cu and Ni plays in the decay of the $n = 1$ image state on these surfaces was investigated by Gao and Lundqvist [\[91\]](#page-15-55). In this work, the image-state wave functions were also approximated by hydrogenic-like wave functions of the form of Eq. [\(24\)](#page-3-2) with no penetration into the solid, a simplified parametrized form was used for the Shockley surfacestate wave function, and screening effects were neglected altogether. A G^0W^0 calculation of the imaginary part of the electron self-energy near a jellium surface was also reported [\[92](#page-16-0)], showing the key role that a full evaluation of this quantity may play in the description of surface-state lifetimes.

The first self-consistent many-body calculations of image-state lifetimes on noble and simple metals were reported by Chulkov et al. [\[51,](#page-15-15) [93\]](#page-16-1), and good agreement with the experimentally determined decay times [\[94](#page-16-2), [95](#page-16-3), [96\]](#page-16-4) was found. In these calculations, all wave functions and energies were obtained by solving a single-particle Schrödinger equation with the physically motivated 1D model potential of Ref. [\[49](#page-15-10)], and the electron self-energy was evaluated in the G^0W^0 approximation. The potential variation in the plane of the surface was considered later through the introduction of an effective mass [\[48\]](#page-15-13), and self-consistent calculations of the key role that the partially occupied Shockley surface state plays in the decay of image states on $Cu(111)$ were carried out [\[48\]](#page-15-13). The inclusion of xc effects was investigated in the framework of the GWΓ approximation, first with an adiabatic local-density description [\[97](#page-16-5)] and more recently with an adiabatic non-local description of the xc kernel [\[98\]](#page-16-6).

The impact of xc effects on the imaginary part of the effective screened interaction of Eq. [\(46\)](#page-7-3) in the vicinity of the (100) and (111) surfaces of Cu and Au is illustrated in Fig. [6,](#page-10-0) where ANLDA calculations of $\text{Im}[\tilde{W}(z, z'; q, \omega)]$ (with full inclusion of xc effects) are compared to calculations of $\text{Im}[W(z, z'; k, \omega)]$ with (ANLDA) and without (RPA) xc effects. Exchange-correlation effects included in the effective screened interaction have two sources. First, there is the reduction of the screening due to the presence of an xc hole associated with all electrons in the Fermi sea [see Eq. [\(48\)](#page-7-4)], which is included in the calculations represented in Fig. [6](#page-10-0) by thick solid lines and also in the calculations represented by dotted lines. Secondly, there is the reduction of the effective screened interaction itself due to the xc hole associated with the excited electron or hole [see Eq. [\(46\)](#page-7-3)], which is only included in the calculations represented in Fig. [6](#page-10-0) by thick solid lines. These contributions have opposite signs, thereby bringing the ANLDA Im $[\tilde{W}(z, z'; k, \omega)]$ (thick solid lines) back to the RPA $\text{Im}[W(z, z'; k, \omega)]$ (thin solid lines).

Figure [7](#page-10-1) exhibits G^0W^0 , G^0W , and $GW\Gamma$ calculations of the imaginary part of the k-resolved $n = 1$

FIG. 6: Imaginary part of the screened interaction $W(z, z'; q, \omega)$ and the effective screened interaction $\tilde{W}(z, z'; q, \omega)$, as a function of $z = z'$ for a fixed value of $k \left(q = 0.5 \text{ Å}^{-1} \right)$ and various values of $\omega \left(\omega = 1, 2, 3, 4 \text{ eV} \right)$, in the vicinity of the (100) and (111) surfaces of Cu and Au. ANLDA calculations of Im $[\tilde{W}(z, z'; q, \omega)]$ are represented by thick solid lines. RPA and ANLDA calculations of $\overline{\text{Im}}[W(z, z'; q, \omega)]$ are represented by thin solid and dotted lines, respectively. The RPA Im $[W(z, z'; q, \omega)]$ and the ANLDA Im $[W(z, z'; q, \omega)]$ are nearly indistinguishable, as a result of a cancellation between the xc effects due to the presence of (i) an xc hole associated with all electrons in the Fermi sea and (ii) an xc hole associated with the excited

FIG. 7: G^0W^0 (G^0W -RPA), G^0W , and $GW\Gamma$ calculations of the imaginary part of the $n = 1$ image-state self-energy $\Sigma(z, z'; \mathbf{k} = 0, \varepsilon_{\mathbf{k}})$, versus z, in the vicinity of the (100) surfaces of Cu and Au. The solid circle represents the value of z ′ in each case. GWΓ calculations (as obtained with the use of our ANLDA xc kernel) are represented by thick solid lines. G^0W (also using our ANLDA xc kernel) and G^0W^0 calculations are represented by dotted and thin solid lines, respectively. ALDA calculations, not plotted in this figure, are found to nearly concide with ANLDA calculations.

TABLE II: Reciprocal lifetimes, in linewidth units (meV), of the $n = 1$ image state (at $\overline{\Gamma}$, i.e., $\mathbf{k} = 0$) on Cu(100), together with the most recent measurement reported in Ref. [\[100](#page-16-7)]. All the single-particle wave functions and energies entering Eqs. (4) , (8) , (16) , and (18) have been chosen to be the eigenfunctions and eigenvalues of the 1D Hamiltonian of Chulkov *et al.* [\[49](#page-15-10)]. Effective masses for all the single-particle energies entering Eqs. [\(8\)](#page-2-3), [\(16\)](#page-3-5), and [\(18\)](#page-3-6) have been set equal to either the free-electron mass $(m_f = 1)$ or to realistic values $(m_f \neq 1)$. Various models have been considered for the description of the electron self-energy, as obtained from (i) Eq. [\(8\)](#page-2-3) with the screened interaction of Eq. [\(38\)](#page-6-2) (SRM), of Eqs. [\(52\)](#page-7-8)-[\(58\)](#page-8-2) (PZ), and of Eqs. [\(45\)](#page-7-2) and [\(48\)](#page-7-4) with $f^{xc}[n_0](z, z'; q, \omega)$ set equal to zero (G^0W^0) , (ii) Eq. [\(16\)](#page-3-5) with the screened interaction of Eqs. [\(45\)](#page-7-2) and [\(48\)](#page-7-4) and the ANLDA xc kernel $f^{xc}[n_0](z, z'; q, \omega)$ $(G^{0'}W)$, and (iii) Eq. [\(18\)](#page-3-6) with the effective screened interaction of Eqs. [\(46\)](#page-7-3) and [\(48\)](#page-7-4) and the ANLDA xc kernel $f^{xc}[n_0](z, z'; q, \omega)$ (GWL).

m_f	Self-energy		Bulk Vacuum	Mix	Total	Exp.
$=1$	SRM	18	3	-4	17	
$=1$	РZ		55		55	
$=1$	G^0W^0	24	14	-16	22	
$\neq 1$	G^0W^0		11.5	-1	17.5	
$\neq 1$	G^0W				24.5	
$\neq 1$	GWT	6.5	11.5	-1	17	
						16

TABLE III: As in Table [II,](#page-11-0) but for Cu(111) and together with the reciprocal lifetime experimentally determined for this surface at low temperature, $T = 25 \text{ K}$ [\[95\]](#page-16-3).

image-state self-energy $\Sigma(z, z'; \mathbf{k} = 0, \varepsilon_{\mathbf{k}})$, versus z, in the vicinity of the (100) surfaces of Cu and Au, with use (in the case of the G^0W and GWT approximations) of the adiabatic nonlocal xc kernel (ANLDA) described in Sec. [III D 5.](#page-8-3) This figure shows that as occurs in the case of the screened interaction xc effects partially compensate each other, leading to an overall effect of no more than 5% percent. We note that, as anticipated in Ref. [\[98](#page-16-6)] for the case of Cu(111), although the ALDA leads to spurious results for the screened interaction our more realistic ANLDA kernel yields self-energies that esentially coincide with those obtained in the ALDA.

Tables [II](#page-11-0) and [III](#page-11-1) exhibit the linewidth of the $n = 1$ image state (at $\bar{\Gamma}$, i.e., $\mathbf{k} = 0$) on the (100) and (111) surfaces of Cu, as obtained from Eq. [\(4\)](#page-2-0) with (i) the imagestate wave function of Chulkov et al. [\[49](#page-15-10)] described in Sec. [III C 2](#page-4-3) and (ii) various approximations for the self-

energy: SRM , PZ , G^0W^0 , G^0W , and $GW\Gamma$. Contributions to the linewidth are separated as follows

$$
\Gamma_{ee} = \Gamma_{bulk} + \Gamma_{vac} + \Gamma_{mix},\tag{70}
$$

where Γ_{bulk} , Γ_{vac} , and Γ_{mix} represent bulk, vacuum, and mixed contributions, respectively, as obtained by confin-ing the integrals in Eqs. [\(4\)](#page-2-0) to either bulk $(z < 0, z' < 0)$, vacuum $(z > 0, z' > 0)$, or mixed $(z \geq 0, z' \leq 0$ or $z \leq 0, z' \geq 0$ coordinates.

First of all, we set all effective masses equal to the free-electron mass, and focus on the role that an accurate description of the screened interaction plays in the coupling of image states with the solid, by comparing to the results obtained (within the G^0W^0 approximation) with the use of the SRM screened interaction and (for the vacuum linewidth) the screened interaction of Persson and Zaremba (PZ). We note that simplified jellium models for the evaluation of the screened interaction yield unrealistic results for the image-state lifetime. Bulk contributions to the linewidth are approximately well described within the SRM, small differences resulting from an approximate description, within this model, of the so-called begrenzung or boundary-effect first described by Ritchie [\[99\]](#page-16-8). However, as quantum-mechanical details of the surface are ignored within this model, it fails to describe both vacuum and mixed contributions to the decay rate. These quantum-mechanical details of the surface are approximately taken into account within the PZ approach, but the PZ model cannot account for the coupling of the image state with the crystal that occurs through the penetration of the image-state wave function into the solid. Discrepancies between vacuum contributions obtained in this model and in the more realistic full G^0W^0 approach appear as a result of the PZ model being accurate only for small **q** wave vectors and ω frequencies.

Now we account for the variation of the potential in the plane of the surface through the introduction of a realistic effective mass for all surface and bulk states. The effective masses of the $n = 1$ image state on Cu(100) and Cu(111) are close to the free-electron mass $(m_i = 1)$. Nevertheless, the effective mass of the $n = 0$ Shockley surface state of Cu(111) and the unoccupied bulk states in $Cu(111)$ and $Cu(100)$, which all contribute to the decay of the $n = 1$ image state, considerably deviate from the free-electron mass; Tables [II](#page-11-0) and [III](#page-11-1) show that the impact of this deviation on the $n = 1$ image-state lifetime is not neglegible.

As for the impact of short-range xc effects, which are fully incorporated in the framework of the GWT approximation, Tables [II](#page-11-0) and [III](#page-11-1) show that the overall impact of these effects is small and $GW\Gamma$ reciprocal lifetimes are close to their G^0W^0 counterparts.

ALDA and ANLDA GWΓ calculations of the reciprocal lifetimes of the $n = 1$ image state on Au(100), never reported before, are exhibited in Table [IV.](#page-12-0) For comparison, this Table also shows G^0W^0 and G^0W calculations, which in the case of the G^0W have been obtained by considering (as within the GWΓ approximation) both local

TABLE IV: G^0W^0 , G^0W , and $GW\Gamma$ reciprocal lifetimes, in linewidth units (meV), of the $n = 1$ image state (at $\overline{\Gamma}$, i.e., $\mathbf{k} = 0$) on Au(100). In the case of the $\vec{G}^0 W$ and $\vec{G} W \Gamma$ reciprocal lifetimes, both ALDA and ANLDA xc kernels have been considered.

xc kernel	G^0W^0	G^0W	GWT
ALDA	30	42.5	31
ANLDA		43	31

TABLE V: Linewidth (inverse lifetime) of image states, in meV. The lifetime in fs $(1 \text{ fs} = 10^{-15} \text{ s})$ is obtained by noting that $\hbar = 658 \,\mathrm{meV}$ fs. The numbers in brackets represent the corresponding references. Electron-phonon linewidths are not included, since in the case of image states they are all expected to be below 1 meV [\[35](#page-14-34)].

 $^a \mathrm{At}$ $T = 25 \, \mathrm{K}.$

 ${}^{b}\text{At} T = 100 \text{ K}.$

 c This work.

(ALDA) and nonlocal (ANLDA) xc kernels. As occurs in the case of Cu [\[98](#page-16-6)], the results shown in Table [IV](#page-12-0) indicate that (i) a realistic adiabatic nonlocal description of xc effects yields reciprocal lifetimes of image states that esentially coincide with those obtained in the ALDA, and (ii) the overall effect of short-range exchange and correlation is small, thereby GWΓ reciprocal lifetimes being close to their G^0W^0 counterparts.

In Table [V,](#page-12-1) we compare self-consistent G^0W^0 and GWΓ (as obtained with the ANLDA xc kernel) calculations (with full inclusion of realistic values of the effective mass of all bulk and surface states) with the existing TR-2PPE data for the $n = 1$ image state at the $\overline{\Gamma}$ point $(k = 0)$ on various simple, noble, and transition single-crystal surfaces. This table shows that G^0W^0 and GWΓ calculations are both in good agreement with TR-2PPE measurements except in the case of the (111) surfaces of the noble metal Ag and the transition metal Ni. The largest disagreement occurs in the case of Ni(111), where the G^0W^0 linewidth is smaller than the measured linewidth by approximately a factor of 2. This can be attributed to the necessity of a full ab initio description of the dynamical response of both sp and d electrons along the lines of Sec. [III D 7.](#page-9-1)

The role that occupied d bands play in the dynamics of image states on silver surfaces was investigated in Ref. $[56]$ along the lines described in Sec. [III D 6.](#page-9-2) It was concluded that d electrons do play an important role as a consequence of the reduction (in the presence of d electrons) of the surface-plasmon energy that allows the opening of a new decay channel. No surface-plasmon decay channel is opened, however, in the case of the other noble-metal surafces (Cu and Au), since in the presence of d electrons the Cu and Au surface-plasmon energy is still too large.

B. Shockley states

 G^0W^0 calculations of the e-e inelastic lifetimes of excited holes at the surface-state band edge of the (111) surfaces of the noble metals Cu, Ag, and Au were first reported in Refs. [\[29\]](#page-14-28) and [\[108\]](#page-16-16) within the 1D scheme of Chulkov *et al.* [\[49\]](#page-15-10) (see Sec. [III C 2\)](#page-4-3), accounting for the potential variation in the plane of the surface through the introduction of a realistic effective mass for the dispersion curve of both bulk and surface states. Within this model, however, all Shockley states have the same effective mass and the projected band structure is still inaccurate, especially at energies above the Fermi level, as shown in Fig. [4](#page-5-0) for Cu(111). As an alternative to the 1D model potential of Chulkov et al. [\[49\]](#page-15-10), Vergniory et al. [\[53\]](#page-15-17) introduced the k-dependent 1D potential of Eq. [\(28\)](#page-5-1) that is constructed to reproduce the bulk energy bands and surface-state energy dispersion obtained from 3D first-principles calculations.

Table [VI](#page-13-0) shows a comparison between the G^0W^0 calculations reported in Refs. [\[29](#page-14-28), [108\]](#page-16-16) and [\[53\]](#page-15-17) for the inelastic lifetime of an excited hole at the band edge of the Shockley surface-state band of $Cu(111)$, as obtained from Eqs. [\(4\)](#page-2-0) and [\(5\)](#page-2-5) with the use of the 1D scheme of Chulkov et al. [\[49](#page-15-10)] and with the k-dependent 1D model potential of Eq. [\(28\)](#page-5-1), respectively. The difference between the surface-state lifetime broadening of 25 eV reported in Refs. [\[29](#page-14-28)] and [\[108\]](#page-16-16) and the more accurate lifetime broadening of 19 eV reported in Ref. [\[53\]](#page-15-17) is entirely due to a more accurate description in Ref. [\[53](#page-15-17)] of (i) the projected band structure and (ii) the wave-vector dependence of the surface-state wave functions entering the evaluation of the self-energy. G^0W and $GW\Gamma$ calculations were reported in Ref. [\[98\]](#page-16-6), showing that as in the case of image states GWΓ linewidths are only slightly lower than their G^0W^0 counterparts.

At this point, we note that the linewidths of the Cu(111) Shockley state at $\overline{\Gamma}$ based on the use of the two 1D models of Sec. [III C 2](#page-4-3) to describe the *initial* surfacestate wave function (at $\bar{\Gamma}$) agree within less than 1 meV. The linewidths also agree within less than 1 meV when the actual surface-state dispersion (thick solid line of Fig. [4\)](#page-5-0) is replaced by the parabolic surface-state disper-

TABLE VI: G^0W^0 , G^0W , and $GW\Gamma$ decay rates, in linewidth units (meV), of an excited hole at the band edge of the Shockley surface-state band of Cu(111) ($E_i = -0.44 \text{ eV}$ and $k_i = 0$). The G^0W^0 calculations have been performed either with the use of the k-dependent 1D model potential of Eq. [\(28\)](#page-5-1), as reported in Ref. [\[53](#page-15-17)], or with the use of the 1D scheme of Chulkov *et al.* [\[49\]](#page-15-10), as reported in Refs. [\[29](#page-14-28)] and [\[108](#page-16-16)]. The G^0W and $GW\Gamma$ calculations have been performed with the use of the 1D scheme of Chulkov *et al.* [\[49\]](#page-15-10), as reported in Ref. [\[98\]](#page-16-6). The experimental linewidth has been taken from the STM measurements reported in Ref. [\[29](#page-14-28)]. The total decay rate Γ_{total} includes the e-ph decay rate of 7 meV reported in Ref. [\[34\]](#page-14-33). Γinter and Γintra represent interband and intraband contributions to the e-e decay rate Γ_{e-e} ; these contributions come from the decay of the excited hole trhough the coupling with bulk states (interband contribution) or thorugh the coupling, within the surface-state band itself, with surface states of different wave vector k parallel to the surface (intraband contribution).

	$\Gamma_{\rm inter}$	$\Gamma_{\rm intra}$	$\Gamma_{\rm e-e}$	$\Gamma_{\rm total}$
$G^{0}W^{0}$ [53]	10		19	26
G^0W^0 [29, 108]		19	25	32
G^0W [98]			30.5	37.5
GWT [98]			24.5	31.5
Experiment				24

TABLE VII: G^0W^0 , G^0W , and $GW\Gamma$ reciprocal lifetimes, in linewidth units (meV), of the $n = 0$ Shockley state (at $\overline{\Gamma}$, i.e., $\mathbf{k} = 0$ on Au(111). In the case of the $G^0 W$ and \overline{GWT} reciprocal lifetimes, both ALDA and ANLDA xc kernels have been considered.

sion of the form dictated by the thin solid line of Fig. [4.](#page-5-0) However, if one replaces in the calculation of Ref. [\[53\]](#page-15-17) the wave-vector dependent surface-state orbitals obtained by solving a 1D Schrödinger equation with the potential of Eq. [\(28\)](#page-5-1) by their less accurate counterparts used in Refs. [\[29\]](#page-14-28) and [\[108\]](#page-16-16), the lifetime broadening is increased considerably (from 19 to 25 meV), showing the important role that the actual coupling between initial and final states plays in the surface-state decay mechanism.

ALDA and ANLDA GWΓ calculations of the reciprocal lifetimes of the Shockley surface state on Au(111), never reported before, are exhibited in Table [VII.](#page-13-1) For comparison, this Table also shows G^0W^0 and G^0W calculations, which in the case of the G^0W have been obtained by considering (as within the GWΓ approximation) both local (ALDA) and nonlocal (ANLDA) xc kernels. As occurs in the case of Cu [\[98](#page-16-6)], the results shown in Table [VII](#page-13-1) indicate that (i) a realistic adiabatic nonlocal description of xc effects yields reciprocal lifetimes of Shockley states that esentially coincide with those obtained in the ALDA,

TABLE VIII: Linewidth (inverse lifetime) of Shockley states, in meV. The lifetime in fs $(1 \text{ fs} = 10^{-15} s)$ is obtained by noting that $\hbar = 658 \,\mathrm{meV}$ fs. The numbers in brackets represent the corresponding references. The calculated values (Γ_{calc}) are decomposed into e-e (Γ_{e-e}) and e-ph (Γ_{e-ph}) contributions. Since GWΓ e-e linewidths are found to be very close to their G^0W^0 counterparts, only G^0W^0 calculations of the e-e linewidth are included here. In the case of Be(0001), calculations have been performed either with the use of the 1D scheme of Chulkov *et al.* [\[49](#page-15-10)], as reported in Ref. [\[110\]](#page-16-18), or via a fully *ab initio* scheme along the lines of Sec. [III D 7,](#page-9-1) as reported in Ref. $[113]$. In the case of Cu(111), calculations have been performed either with the use of the k-dependent 1D model potential of Eq. [\(28\)](#page-5-1), as reported in Ref. [\[53](#page-15-17)], or with the use of the 1D scheme of Chulkov *et al.* [\[49](#page-15-10)], as reported in Refs. [\[29](#page-14-28)] and [\[108](#page-16-16)].

^aAt room temperature.

and (ii) the overall effect of short-range exchange and correlation is small, thereby GWΓ reciprocal lifetimes being close to their G^0W^0 counterparts.

The calculated and experimental linewidths of Shockley states at the Γ point of a variety of simple and noble metal surfaces are collected in Table [VIII.](#page-13-2) It had been argued in Ref. [\[86\]](#page-15-49) that in the case of the noble metals deviations from electron dynamics in a free gas of sp electrons due to the participation of d electrons in the screening of e-e interactions are of key importance in the determination of the inelastic lifetime of bulk electronic states. Hence, Kliewer et al. [\[29](#page-14-28)] added this effect to the calculated Γ_{e-e} following the approach originally suggested by Quinn [\[114\]](#page-16-21); they concluded that the screening of d electrons reduces the e-e scattering considerably, thus improving the agreement with experiment. Nevertheless, it was shown in Ref. [\[56\]](#page-15-51) that in the case of Shockley states, whose decay is dominated by intraband transitions that are associated with very small values of the momentum transfer, the screening of d electrons is expected to reduce the lifetime broadening only very slightly. Indeed, adding to the estimated Cu(100) Shockley $e-e$ linewidth at $\overline{\Gamma}$ reported recently in Ref. [\[53](#page-15-17)] (with no d-screening reduction) the e-ph linewidth of 7 meV reported in Ref. [\[34\]](#page-14-33), the calculated total linewidth is found to be $\Gamma_{calc} = 26$ meV in close agreement with the exprimentally measured linewidth of 24 meV, as shown in Table [VIII.](#page-13-2) An extension of the approach reported in Ref. [\[53\]](#page-15-17) to the case of the other noble metals Ag and Au should yield calculated linewidths that are closer to

experiment than those reported in Refs. [\[29\]](#page-14-28) and [\[108\]](#page-16-16).

The lifetime broadening of excited Shockley electrons beyond the $\bar{\Gamma}$ point (with $\mathbf{k} \neq 0$ and energies above the Fermi level - see Fig. [1\)](#page-0-0) was studied with the STM by Bürgi et al. [\[30](#page-14-29)] on Cu(111) and by Vitali et al. [\[115\]](#page-16-22) and Kliewer *et al.* [\[116\]](#page-16-23) on Ag(111). The corresponding G^0W^0 calculations that follow the 1D scheme of Chulkov et al. [\[49\]](#page-15-10) were reported in Refs. [\[117](#page-16-24)] and [\[115\]](#page-16-22) for $Cu(111)$ and $Ag(111)$, respectively, but now accounting for the potential variation parallel to the surface by introducing not only a realistic effective mass for all bulk and surface states but also surface-state orbitals that change with **k** along the surface-state dispersion curve. More accurate calculations were later reported in the case of $Cu(111)$ [\[53\]](#page-15-17) with the use of the **k**-dependent 1D model potential of Eq. [\(28\)](#page-5-1), showing that the inelastic lifetimes of excited Shockley electrons happen to be very sensitive to the actual shape of the surface-state single-particle orbitals beyond the $\overline{\Gamma}$ point. A comparison between these more refined calculations and experiment demonstrated that there is close agreement at the surface-state band

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edge, i.e., at $\overline{\Gamma}$, as shown in Tables [VI](#page-13-0) and [VIII,](#page-13-2) and there is also reasonable agreement at low excitation energies above the Fermi level. At energies where the surface-state band merges into the continuum of bulk states, however, the calculated linewidths are found to be too low, which should be a signature of the need of a fully 3D description of the surface band structure.

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